
HVR100

Variable Capacitance Diode for AM tuner

HITACHI

ADE-208-079E (Z)

Rev. 5
Dec. 1998

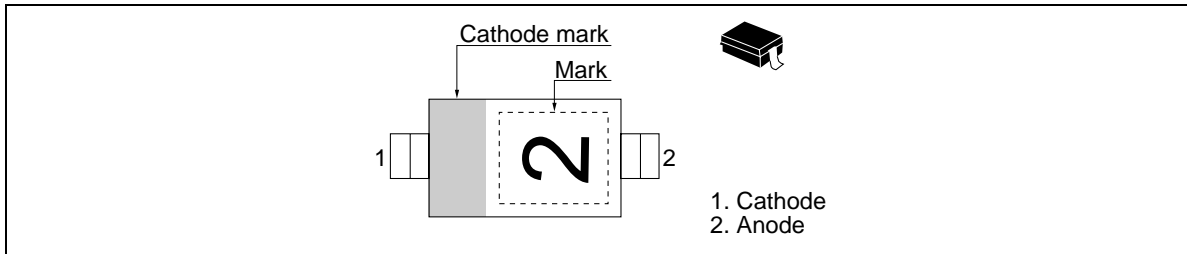
Features

- High capacitance ratio. ($n = 16.0$ min)
- High figure of merit. ($Q = 200$ min)
- To be usable at low voltage.
- Small Resin Package (SRP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVR100	2	SRP

Outline



HVR100

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V _R	15	V
Junction temperature	T _j	125	°C
Storage temperature	T _{stg}	-55 to +125	°C

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse voltage	V _R	15	—	—	V	I _R = 10μA
Reverse current	I _R	—	—	100	nA	V _R = 9V
Capacitance	C ₁	421.5	—	524.6	pF	V _R = 1V, f = 1 MHz
	C ₃	182.0	—	275.7		V _R = 3V, f = 1 MHz
	C ₅	73.2	—	121.4		V _R = 5V, f = 1 MHz
	C ₆	42.2	—	72.2		V _R = 6V, f = 1 MHz
	C ₇	26.2	—	41.6		V _R = 7V, f = 1 MHz
	C ₈	20.4	—	28.2		V _R = 8V, f = 1 MHz
Capacitance ratio	n	16	—	—	—	C ₁ / C ₈
Figure of merit	Q	200	—	—	—	C = 450pF, f = 1 MHz
Matching error	ΔC/C ¹	—	—	3.0	%	V _R = 1 to 8V
ESD-Capability ¹	—	80	—	—	V	C=200pF, Both forward and reverse direction 1 pulse.

Notes 1. C.C system (Continuous Connected taping system) enable to make any 10 pcs of ΔC/C continuous in a reel, expect extention to another group.
Calculate Matching Error,

$$\Delta C/C = \frac{(C_{max} - C_{min})}{C_{min}} \times 100 (\%)$$

Notes 2. Failure criterion ; IR ≥ 100nA at VR = 9 V

Main Characteristic

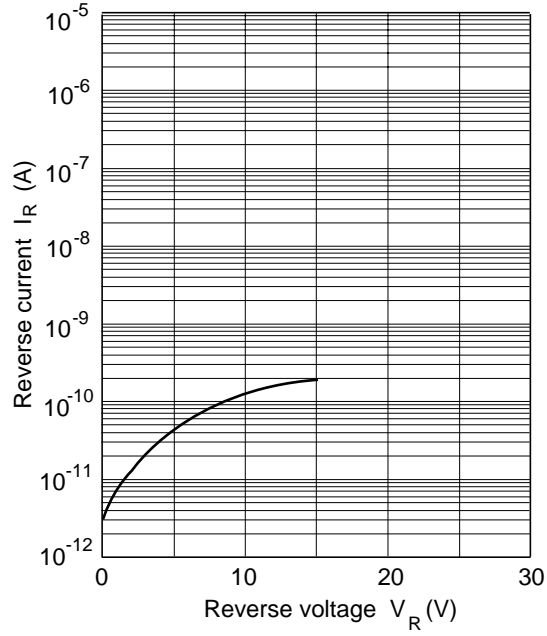


Fig.1 Reverse current Vs. Reverse voltage

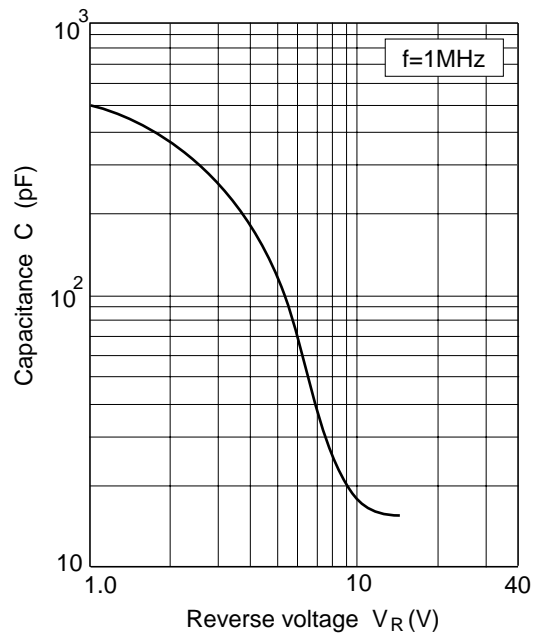
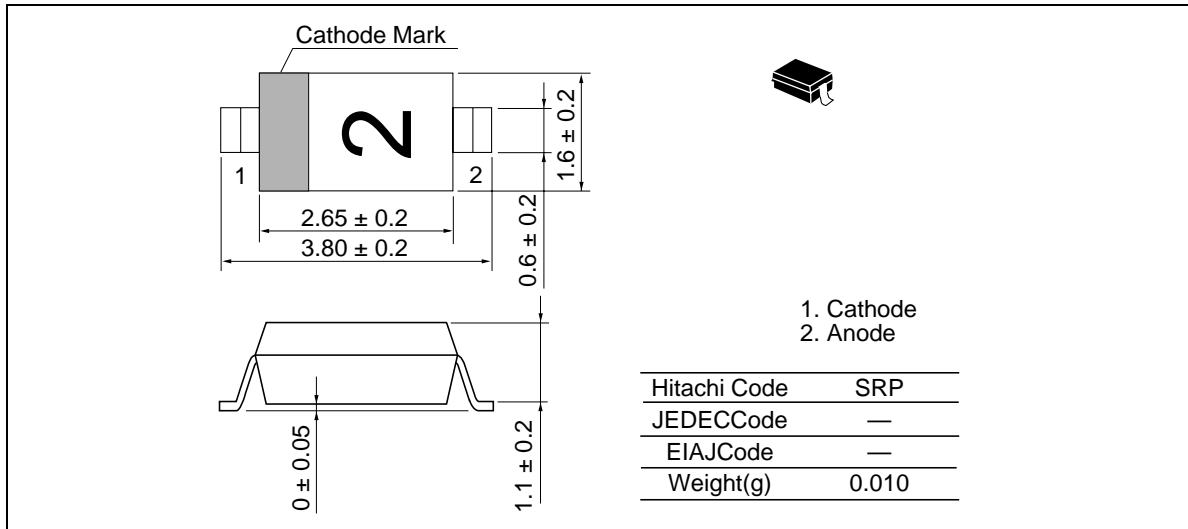


Fig.2 Capacitance Vs. Reverse voltage

HVR100

Package Dimensions

Unit : mm



Disclaimer

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

Sales Offices

HITACHI**Hitachi, Ltd.**

Semiconductor & Integrated Circuits
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : <http://semiconductor.hitachi.com/>
 Europe : <http://www.hitachi-eu.com/hel/ecg>
 Asia : <http://sicapac.hitachi-asia.com>
 Japan : <http://www.hitachi.co.jp/Sicd/indx.htm>

For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe Ltd.
Electronic Components Group
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585200

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00
Singapore 049318
Tel: <65>-538-6533/538-8577
Fax: <65>-538-6933/538-3877
URL: <http://www.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road
Hung-Kuo Building
Taipei (105), Taiwan
Tel: <886>-(2)-2718-3666
Fax: <886>-(2)-2718-8180
Telex: 23222 HAS-TP
URL: <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon
Hong Kong
Tel: <852>-(2)-735-9218
Fax: <852>-(2)-730-0281
URL: <http://semiconductor.hitachi.com.hk>

Copyright © Hitachi, Ltd., 2001. All rights reserved. Printed in Japan.
Colophon 4.0